MJE15032 (NPN), MJE15033 (PNP)

Preferred Devices

Complementary Silicon Plastic Power Transistors

Designed for use as high-frequency drivers in audio amplifiers.

Features

• DC Current Gain Specified to 5.0 Amperes

 $\begin{array}{l} h_{FE} \, = 70 \; (Min) \; @ \; I_{C} = 0.5 \; Adc \\ = 10 \; (Min) \; @ \; I_{C} = 2.0 \; Adc \end{array}$

• Collector-Emitter Sustaining Voltage -

 $V_{CEO(sus)} = 250 \text{ Vdc (Min)} - \text{MJE}15032, \text{MJE}15033$

• High Current Gain – Bandwidth Product

 $f_T = 30 \text{ MHz (Min)} @ I_C = 500 \text{ mAdc}$

• TO-220AB Compact Package

• Epoxy Meets UL 94 V-0 @ 0.125 in

• ESD Ratings: Machine Model C

Human Body Model 3B

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	250	Vdc
Collector-Base Voltage	V_{CB}	250	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous – Peak	I _C	8.0 16	Adc
Base Current	Ι _Β	2.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	50 0.40	W W/°C
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	2.0 0.016	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



ON Semiconductor®

8.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 250 VOLTS, 50 WATTS

MARKING DIAGRAM



TO-220 CASE 221A STYLE 1



MJE1503x = Specific Device Code

x = 2 or 3

A = Assembly Location

Y = Year
W = Work Week
G = Pb-Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MJE15032	TO-220	50 Units/Rail
MJE15032G	TO-220 (Pb-Free)	50 Units/Rail
MJE15033	TO-220	50 Units/Rail
MJE15033G	TO-220 (Pb-Free)	50 Units/Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MJE15032 (NPN), MJE15033 (PNP)

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

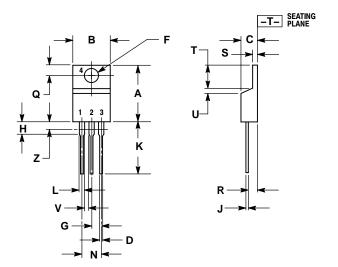
Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (Note 1) $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	250	-	Vdc	
Collector Cutoff Current (V _{CB} = 250 Vdc, I _E = 0)	I _{CBO}	-	10	μAdc	
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	-	10	μAdc	
ON CHARACTERISTICS (Note 1)					
DC Current Gain $ \begin{aligned} &(I_C=0.5 \text{ Adc, } V_{CE}=5.0 \text{ Vdc}) \\ &(I_C=1.0 \text{ Adc, } V_{CE}=5.0 \text{ Vdc}) \\ &(I_C=2.0 \text{ Adc, } V_{CE}=5.0 \text{ Vdc}) \end{aligned} $	h _{FE}	70 50 10	_ _ _	-	
Collector–Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)	V _{CE(sat)}	-	0.5	Vdc	
Base–Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	-	1.0	Vdc	
DYNAMIC CHARACTERISTICS					
Current Gain – Bandwidth Product (Note 2) ($I_C = 500 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f_{test} = 1.0 \text{ MHz}$)	f⊤	30	_	MHz	

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%. 2. $f_T = |h_{fe}| \bullet f_{test}$.

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PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AA**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
7		0.080		2 04

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR